

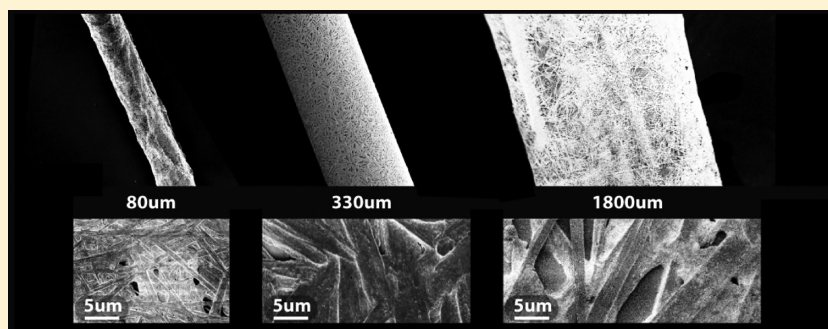
Morphology and Photoluminescence of $\text{CH}_3\text{NH}_3\text{PbI}_3$ Deposits on Nonplanar, Strongly Curved Substrates

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S Supporting Information



ABSTRACT: Organic–inorganic metal halide perovskites have recently attracted increasing attention as highly efficient light harvesting materials for photovoltaic applications. The solution processability of these materials is one of their major advantages on the route toward fabrication of low-cost solar cells and optoelectronic devices. However, the precise control of crystallization and morphology of organometallic perovskites deposited from solutions, considered crucial for enhancing the final photovoltaic performance, still remains challenging. In this context, here, we report on growing microcrystalline deposits of methylammonium lead triiodide perovskite, $\text{CH}_3\text{NH}_3\text{PbI}_3$ (MAPbI₃), by one-step solution casting on cylinder-shaped quartz substrates (rods) having diameters in the range of 80 to 1800 μm . We show that the substrate curvature has a strong influence on morphology of the obtained polycrystalline deposits of MAPbI₃. Specifically, a marked size reduction of MAPbI₃ microcrystallites concomitant with an increased crystal packing density was observed with increasing the substrate curvatures. In contrast, although the crystallite width and length markedly decreased for substrates with higher curvatures, the photoluminescence (PL) spectral peak positions did not significantly evolve for MAPbI₃ deposits on substrates with different diameters. The crystallite size reduction and a denser coverage of microcrystalline MAPbI₃ deposits on cylinder-shaped substrates with higher curvatures were attributed to two major contributions, both related to the annealing step of the MAPbI₃ deposits. In particular, the diameter-dependent variability of the heat capacities and the substrate curvature-enhanced solvent evaporation rate seemed to contribute the most to the crystallization process and the resulting morphology changes of MAPbI₃ deposits on cylinder-shaped quartz substrates with various diameters. The longitudinal geometry of cylinder-shaped substrates provided also a facile solution for checking the PL response of the deposits of MAPbI₃ exposed to the flow of various gaseous media, such as oxygen (O_2), nitrogen (N_2), and argon (Ar). Specifically, under excitation with $\lambda_{\text{exc}} = 546 \text{ nm}$, the rapid and pronounced decreases and increases of PL signals were observed under intermittent subsequent exposures to O_2 and N_2 , respectively. Overall, the approach reported herein inspires novel, cylinder-shaped geometries of MAPbI₃ deposits, which can find applications in low-cost photo-optical devices, including gas sensors.

KEYWORDS: organometallic perovskites, $\text{CH}_3\text{NH}_3\text{PbI}_3$, MAPbI₃, crystallization, substrate curvature, photoluminescence

The organic–inorganic methylammonium lead triiodide, $\text{CH}_3\text{NH}_3\text{PbI}_3$ (MAPbI₃), is a photovoltaic perovskite material with outstanding optoelectronic properties, such as a very high visible light absorption coefficient, balanced electron and hole transport accompanied by high charge carrier mobilities and long diffusion lengths, and a very strong photoluminescence (PL).¹ Not surprisingly, the materials with such favorable optical and electrical properties have been swiftly utilized in solar cells, whose power conversion efficiency

rapidly increased from the initial 3.8%² and 9.7%³ to the recently achieved value of 22.1%,⁴ thus opening a new avenue for emerging applications of metal–organic perovskites in photovoltaic technology.

Recently, in the context of designing new generations of efficient cost-effective solar cells, significant effort has been

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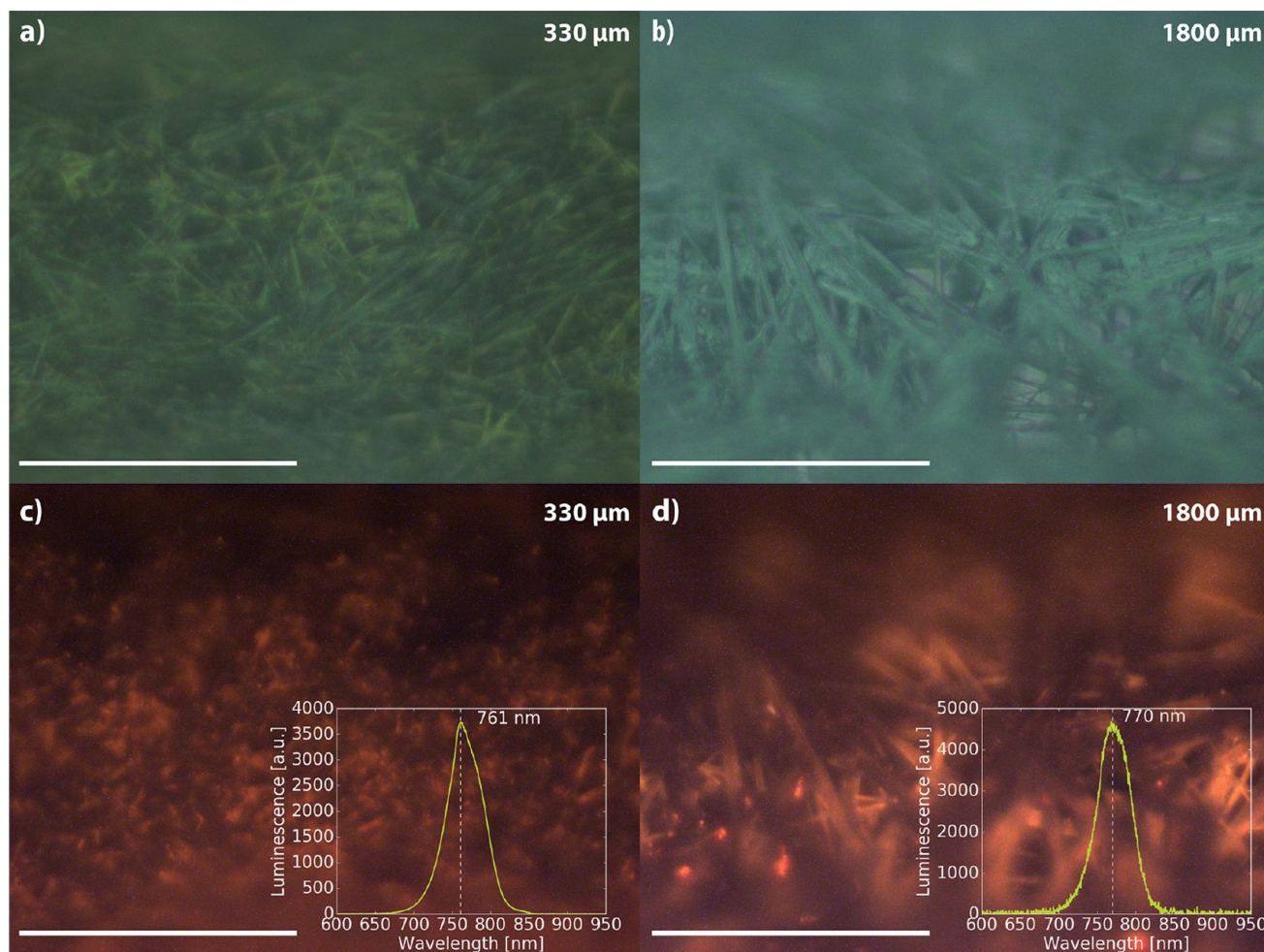


Figure 1. Comparison of the optical microscopy images of MAPbI₃ deposits on cylinder-shaped quartz substrates having diameters of 330 and 1800 μm . Bright-field microscopic images acquired under visible light illumination for the cylinder-shaped substrates with diameters of 330 μm (a) and 1800 μm (b). Corresponding luminescence images collected under excitation with $\lambda_{\text{exc}} = 546 \text{ nm}$ for the MAPbI₃ films deposited on the substrates with diameters of 330 μm (c) and 1800 μm (d). Insets to (c) and (d): the steady-state PL spectra acquired simultaneously with luminescent imaging. In all images the scale bars are set to 50 μm .

devoted toward obtaining uniform and compact thin layers of MAPbI₃. In particular, there have been numerous reports on crystallinity and morphology, as well as PL properties, of MAPbI₃ obtained either in the form of single-crystalline particles^{5,6} or polycrystalline films deposited on planar substrates.^{7,8} It has been generally accepted that the final photovoltaic properties of MAPbI₃-based devices are strongly dependent on the film fabrication process, which defines the uniformity and compactness of thin layers of MAPbI₃.^{9,10}

Various fabrication methods of MAPbI₃ thin films have been reported to date.^{11,12} In general, the most commonly used deposition techniques can be categorized into the one-step precursor deposition methods¹³ and two-step deposition methods.¹⁴ It is customarily accepted that the two-step deposition provides better control of the composition, the thickness, and the morphology of the MAPbI₃-based films, thus leading to higher photovoltaic performances of the final devices.¹⁵ On the other hand, one-step solution-casting protocols seem to be more suitable for manufacturing low-cost MAPbI₃-based devices at large scale.¹⁶ It has also been widely recognized that obtaining densely packed deposits of MAPbI₃ with small grain sizes in the range from hundreds of nanometers to micrometers can be beneficial for numerous

prospective optoelectronic applications, including photo-optical gas sensors.¹⁷

Although monolithic layers of organometallic perovskites are mostly used in photovoltaic applications, coatings having other morphological characteristics are also being intensively explored. In particular, high power conversion efficiency (PCE) of a coating formed by low-dimensional (1D) MAPbI₃ nano- and microstructures has recently been reported by Im et al.¹⁸ Specifically, thin layers consisting of nanowires having a 100 nm diameter and a length of several μm were obtained by two-step spin-coating technology.

The two-step deposition route combining the solution process and vapor phase conversion was used for growing polycrystalline MAPbI₃ microwires with a length of up to 80 μm that revealed both an excellent light-guiding performance with very low optical loss and band-gap tunability.¹⁹ The one-step solution-based synthesis of highly photoactive MAPbI₃ nanowires with mean diameters of 50 to 400 nm and lengths up to 10 μm has also been reported by Horváth et al.²⁰

In this context, here, we report on the fabrication and characterization of polycrystalline deposits of MAPbI₃ on nonplanar, strongly curved substrates. In particular, with using one-step solution casting²¹ on curved cylinder-shaped quartz

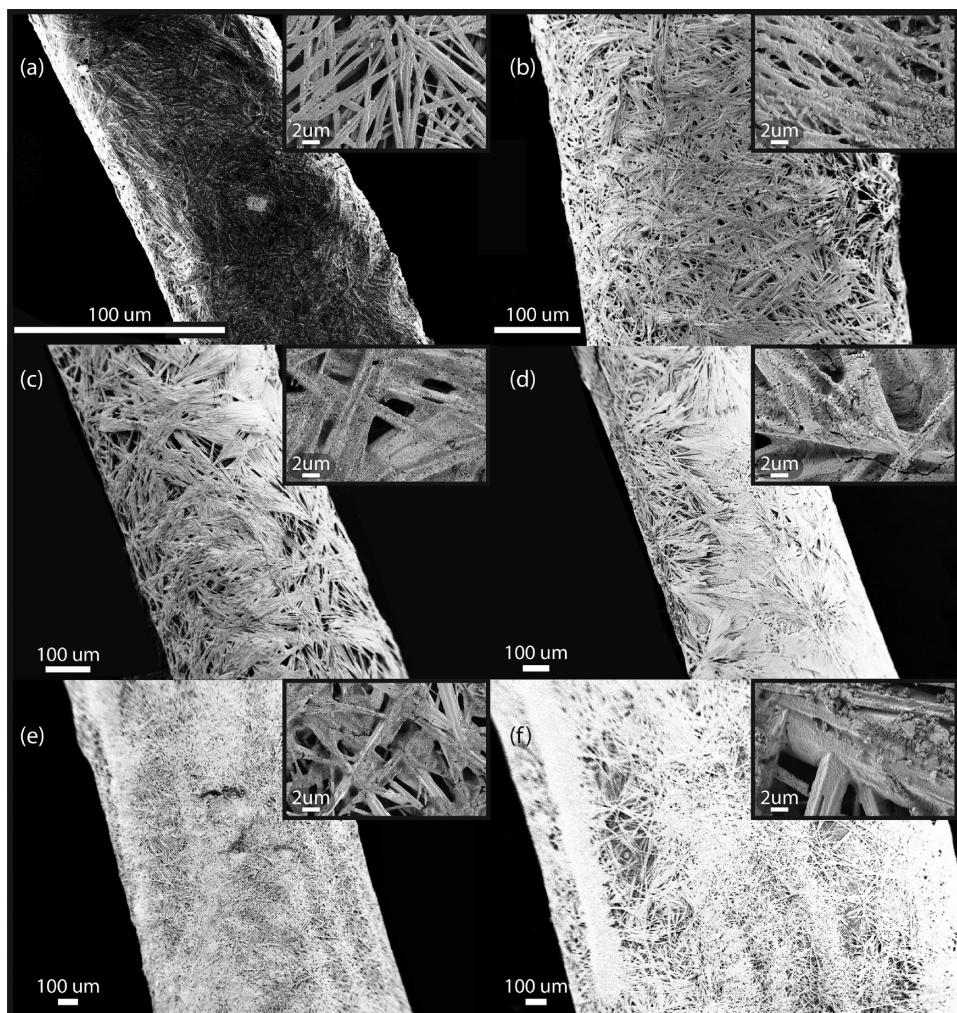


Figure 2. SEM images of microcrystalline MAPbI₃ deposits on cylinder-shaped quartz substrates with varying diameters: (a) 80 μm , (b) 330 μm , (c) 400 μm , (d) 700 μm , (e) 1100 μm , and (f) 1800 μm . The insets show the magnified image of the deposits on the same size rods as the main figure.

substrates with diameters in the range from 80 to 1800 μm we manufactured the MAPbI₃ deposits consisting of polycrystalline microwires with average sizes of 100 nm to 8 μm in diameter and up to ~ 150 μm in length.

The optical microscopy and scanning electron microscopy (SEM) imaging of the obtained deposits revealed a pronounced dependence of their morphology on the substrate curvature. Notably, a markedly enhanced surface grain packing, concomitant with smaller average microcrystallite sizes, was observed while depositing MAPbI₃ on cylinder-shaped quartz substrates with the smallest diameters (i.e., of 80 and 330 μm). Interestingly, however, the microcrystalline MAPbI₃ deposits conserved roughly the same thickness of 12–15 μm throughout the whole range of variability of the substrate diameters.

Since the cylinder-shaped geometry of MAPbI₃ deposits facilitates the design of sealed housings, we also explored a possibility of implementing the obtained microcrystalline densely packed MAPbI₃ films as prospective photo-optical gas sensors. To this end, a cylindrical substrate having a diameter of 330 μm was covered with MAPbI₃ and encapsulated in a section of a slightly larger quartz capillary (3.0 mm i.d./4.0 mm o.d.). This approach provided an easy way for a direct exposure of the MAPbI₃-covered substrate to gaseous media, such as O₂, N₂, and Ar and made it possible to detect gas-dependent changes in the characteristic PL signal of MAPbI₃. Overall, this

construction revealed its usefulness for photo-optical sensing of gaseous media and may serve as a model of uncomplicated MAPbI₃-based gas sensors.

RESULTS AND DISCUSSION

Morphology and Photoluminescence. Optical microscopy and scanning electron microscopy were used as essential analytical tools for checking the morphology and crystallinity of MAPbI₃ deposits on cylinder-shaped quartz substrates. The example optical microscopy images of MAPbI₃ deposits acquired for two substrates with diameters of 330 and 1800 μm are shown in Figure 1 (a and b). As can be seen, the morphology of the polycrystalline deposit on a cylindrical substrate having a diameter (DIA) of 330 μm is distinctively different from the one deposited on the 1800 μm DIA substrate. In particular, the MAPbI₃ deposit on the 330 μm DIA substrate consists of densely packed micrometer-sized wires, having average cross-sectional diameters of 1.0 μm and ~ 20 to 30 μm in length. In contrast, the thin film of MAPbI₃ deposited on the 1800 μm DIA substrate consists of definitely larger, elongated, and branched fibrous structures, having average dimensions of ~ 5 to 8 μm in cross-section and ~ 50 to 70 μm in length.

The luminescence microscopy images, acquired under an excitation of $\lambda_{\text{exc}} = 546$ nm and shown in Figure 1(c and d) also

point to the formation of a MAPbI₃ deposit having markedly different morphologies for 330 and 1800 μm DIA substrates. In particular, the strongly emitting bright spots correspond to the emission occurring essentially from the terminations of micrometer-sized wires, which are mostly longitudinally aligned on the surface of the 330 μm DIA substrate (Figure 1(c)). In contrast, for the 1800 μm DIA substrate (Figure 1(d)), the PL emission can also be seen from the numerous branch-crossing points, which facilitate the light emission from the otherwise elongated light-channeling structures.¹⁹ It should be noted that the CCD camera used in our experimental setup for luminescence imaging was only able to detect the short-wavelength tail of the MAPbI₃ emission. In contrast, the simultaneously acquired PL spectra provided the whole spectral information.

In particular, the PL spectra shown in the insets to Figure 1(c and d), collected for samples deposited on cylinder-shaped substrates with diameters of 330 and 1800 μm and peaking around ~760–770 nm, are characteristic for polycrystalline thin films of MAPbI₃.²² The peak position at 770 nm of the PL spectrum acquired for the deposit coated onto the 1800 μm substrate is slightly red-shifted as reference to the peak position at 761 nm collected for the deposit coated onto the 330 μm substrate. Similarly red-shifted PL spectra have been often reported for larger sizes of MAPbI₃ crystallites^{23,24} and associated with enhanced self-absorption in the larger crystals.²⁵

The PL emission peaks shown in the insets to Figure 1(c and d) are also spectrally broadened, and both reveal a shoulder at longer wavelength. Such broadening of the PL spectra and the presence of a long-wavelength shoulder in the PL emission peaks can be ascribed to the presence of the disordered crystalline phases and shallow trapping levels on the grain boundaries.^{26,27}

Similar PL spectra were observed in this study for all MAPbI₃ deposits on cylinder-shaped substrates (see, for example, Figure S3 for the PL spectrum of MAPbI₃ deposited on the 80 μm DIA capillary). Thus, although the crystallite width and length markedly decreased for substrates with higher curvatures, the PL spectral peak positions and the spectral shapes did not significantly evolve for deposits on substrates with different diameters.

To gain further insight into the morphological differences in crystallinity of MAPbI₃ layers deposited on cylinder-shaped quartz substrates having various diameters, we performed SEM imaging. The conventional SEM images acquired for MAPbI₃ films for the entire range of the substrate diameters (i.e., 80, 330, 400, 700, 1100, and 1800 μm) are shown in Figure 2. As can be seen, the SEM images revealed a marked dependence of the crystallinity and morphology of the thus obtained MAPbI₃ deposits on the substrate diameter. In particular, for quartz rods with smallest diameters (80–330 μm), the MAPbI₃ thin films consisted of densely packed micrometer wires, whereas for the substrates with larger diameters (400–1800 μm) MAPbI₃ formed less densely packed polycrystalline branched and interconnected micrometer-sized ribbon structures, which contained also a large number of voids. Interestingly, however, the microcrystalline MAPbI₃ films deposited on cylinder-shaped quartz substrates conserved roughly the same thickness of 12–15 μm throughout the whole range of variability of the substrate diameters.

Thus, in addition to elongated crystallites, which represent the major morphological feature of MAPbI₃ deposits in this study, we also observe other forms of polycrystalline MAPbI₃,

including small spheres and star-like, leaf-like, or dandelion-type structures. In particular, star-like structures systematically occur for MAPbI₃ deposits coated onto substrates with larger diameters (lower substrate curvatures). For example, such branched structures can be seen in Figure S9 for MAPbI₃ deposits on cylinder-shaped quartz rods having diameters of 400 and 700 μm. In fact, the star-like structures present on cylindrical substrates with larger diameters are similar to these reported by Nie et al. for hot-casting of thin films of MAPbI₃ on flat substrates²⁴ or by Xu et al. for MAPbI₃ thin films deposited onto a flat glass substrate (indium tin oxide) covered with a compact layer of TiO₂.²⁸ Moreover, the optical microscopy image in Figure S4(a) also shows the presence of branched and interconnected ribbons of MAPbI₃ deposited onto a flat glass surface, while employing the one-step solution coating and analogous annealing conditions as used for coating the cylindrical substrates. It has to be stressed that the “voids”, which occur for practically all the deposits presented in Figure 2, are not really free of MAPbI₃. As suggested by Xu et al., the space in between the branched and interconnected micrometer-sized ribbons is also partially filled with smaller, more disordered “spherulitic” crystalline structures of MAPbI₃.²⁸

Overall, the SEM images presented in Figure 2 revealed a strong relationship between the morphology of MAPbI₃ deposits and the substrate curvature. In particular, for the cylinder-shaped quartz substrates with diameters within the range from 80 to 1800 μm, the average sizes of polycrystalline microwires evolved from 100 nm to 8 μm (width) and 5 μm to 150 μm (length).

The mechanisms behind the morphological changes in crystallinity of MAPbI₃ deposits as a function of the substrate curvature are complex and involve quite a number of contributions, such as variability of the heat capacities and substrate surface roughness of quartz rods, surface wetting properties,²⁹ substrate curvature dependent evaporation rates of the solvent (dimethylformamide, DMF), and the local changes in the air flow during annealing of the deposits.

To determine the potential variability of the surface roughness, we used two high-resolution imaging techniques, i.e., SEM and atomic force microscopy (AFM). The SEM images acquired for the uncoated cylindrical quartz substrates of different diameters revealed statistically similar densities of surface defects. Concomitantly, the AFM measurements pointed to a rather low and similar surface roughness (<1.0 nm) for all the quartz substrates. The results of the corresponding SEM and AFM measurements are shown in Figure S13 and Figure S14.

Since in our experimental setup the cylindrical substrates are not in direct contact with the heat source during the annealing process (Figure S1), we also investigated the influence of the variability of substrate heat capacities on the crystallization of MAPbI₃ deposits. A rough estimate of the difference in the heat capacities for the substrate diameter range used in this study (80–1800 μm) yields a relatively large factor of 500. Therefore, to gain further insight into the contribution of the variability of substrate heat capacities, the annealing process at 110 °C was performed for both nonpreheated and preheated substrates. To this end, two cylindrical quartz rods with diameters of 80 and 400 μm were simultaneously wetted with the same volumes (~2.5 μL) of the stoichiometric solution of MAPbI₃ precursors in DMF either outside of the hot plate (nonpreheated substrates) or when the rods were already positioned on the hot plate (preheated substrates). The example results of

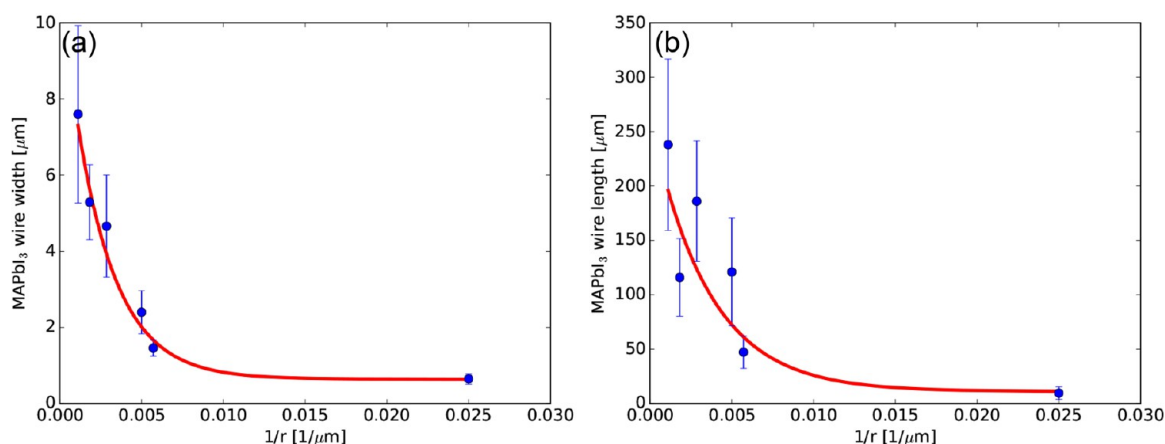


Figure 3. Average characteristic sizes of MAPbI₃ microwires plotted as a function of the substrate curvature ($1/r$): (a) average widths and (b) average lengths. The solid line corresponds to the fit with an exponential function.

annealing of the MAPbI₃ deposits with using these two different scenarios can be viewed in [SI Video_Clip_1](#) and [SI Video_Clip_2](#) for nonpreheated and preheated substrates, respectively.

These video clips reveal that for both scenarios of annealing the crystallization process was definitely much faster for thinner substrates. In particular, for the nonpreheated substrates, the estimated times of MAPbI₃ crystallization were 1 s 120 ms and 12 s 520 ms for quartz rod diameters of 80 and 400 μm, respectively, whereas for the preheated substrates the corresponding time lapses were 880 ms and 5 s. Thus, the corresponding crystallization time ratios were ~ 12 and ~ 5 for the nonpreheated and preheated substrates, respectively. Interestingly, a rough calculation of the difference in the heat capacities for the two quartz substrates with diameters of 80 and 400 μm suggests a factor of ~ 25 .

It should also be noted that in our experimental setup for annealing the coated quartz rods are positioned at a small distance (~ 3.0 mm) from the hot plate ([Figure S1](#)). Therefore, concomitantly with a rather large diameter of the hot plate itself (~ 25.0 cm), the herein used annealing setup provided comparable air-flow conditions for the quartz cylindrical substrates having different diameters.

We additionally checked the influence of the increasing substrate curvature on the solvent evaporation rate during the thermal annealing of the solution-processed MAPbI₃ deposits. The actual influence of the substrate curvature on liquid evaporation rates had been investigated theoretically by William Thomson (also known as Lord Kelvin), who derived the relevant formulas. In principle, the most general form of the Kelvin law ([eq 1](#)) is dependent only upon thermodynamic principles and does not involve specific properties of materials. It describes the change in vapor pressure due to a curved liquid–vapor interface, such as the surface of a droplet:

$$\frac{RT}{M} \ln\left(\frac{P}{P_0}\right) = \pm 2 \frac{\sigma}{d} \left(\frac{1}{r} - \frac{1}{r_0}\right) \quad (1)$$

where R is the gas constant; T , the absolute temperature; M , the molecular weight; σ , the surface energy; d , the density of the liquid; P , the escaping tendency of the substance from a curved surface with radius r ; and P_0 , the escaping tendency from a surface with radius r_0 , where r_0 may be infinitely large, namely, in a flat surface. Thus, as suggested by the Kelvin equation ([eq 1](#)), under the same experimental conditions for

the thermal annealing, the actual evaporation rate of the solvent from strongly curved convex substrates (e.g., quartz rods with very small diameters) should be higher than from substrates with smaller curvatures.^{30,31} In fact, similar phenomena to these observed herein have been reported for numerous systems where the curved geometry of the substrates influenced the solvent evaporation rate at both micro- and macroscales.^{32,33}

To further analyze the size variability of polycrystalline MAPbI₃ microwires on substrates with different radii (r), while based solely on Kelvin's law, the following assumptions can be made:

1. As evidenced by [eq 1](#), the solvent evaporation rate is proportional to $\sim \exp(1/r)$.
2. The nucleation rate of MAPbI₃ crystallites should correlate with the solvent evaporation rate.

These assumptions suggest that the average sizes of the formed microwires should also correlate, at least partially, with the substrate radii. Therefore, one should expect crystallites with smaller sizes for the cylindrical substrates with the decreasing substrate radii (i.e., the increasing substrate curvatures, $1/2r$). Thus, the average sizes of MAPbI₃ microwires should correlate with $\sim \exp(-1/r)$. Based on these assumptions, the estimated vapor pressure change, while varying the substrate diameters in the range of 80 to 1800 μm, is on the order of $\sim 2.5\%$.

The experimentally measured dependencies of average characteristic sizes (widths and lengths) of MAPbI₃ microwires on the substrate curvature are plotted in [Figure 3](#). The corresponding histograms of the crystallite size distributions for each substrate diameter can be found in the [Supporting Information](#) ([Figures S10](#) and [S11](#)). Thus, the exponential decays shown in [Figure 3](#) point to a strong correlation of the characteristic crystallite sizes of MAPbI₃ microwires with the substrate curvature.

Overall, these findings have implications for the field of solution-processed deposition of microcrystalline organometallic perovskites, because they demonstrate that casting and crystallization processes conducted under the same reaction conditions, with the same reaction time, do not produce equivalent deposits; rather, they are dependent on the substrate geometry.

Influence of Gas Flow on Photoluminescence of MAPbI₃ Microwires. The dense coverage with micrometer-sized crystallites, concomitant with a large available active surface, obtained on quartz rods with the smallest diameters

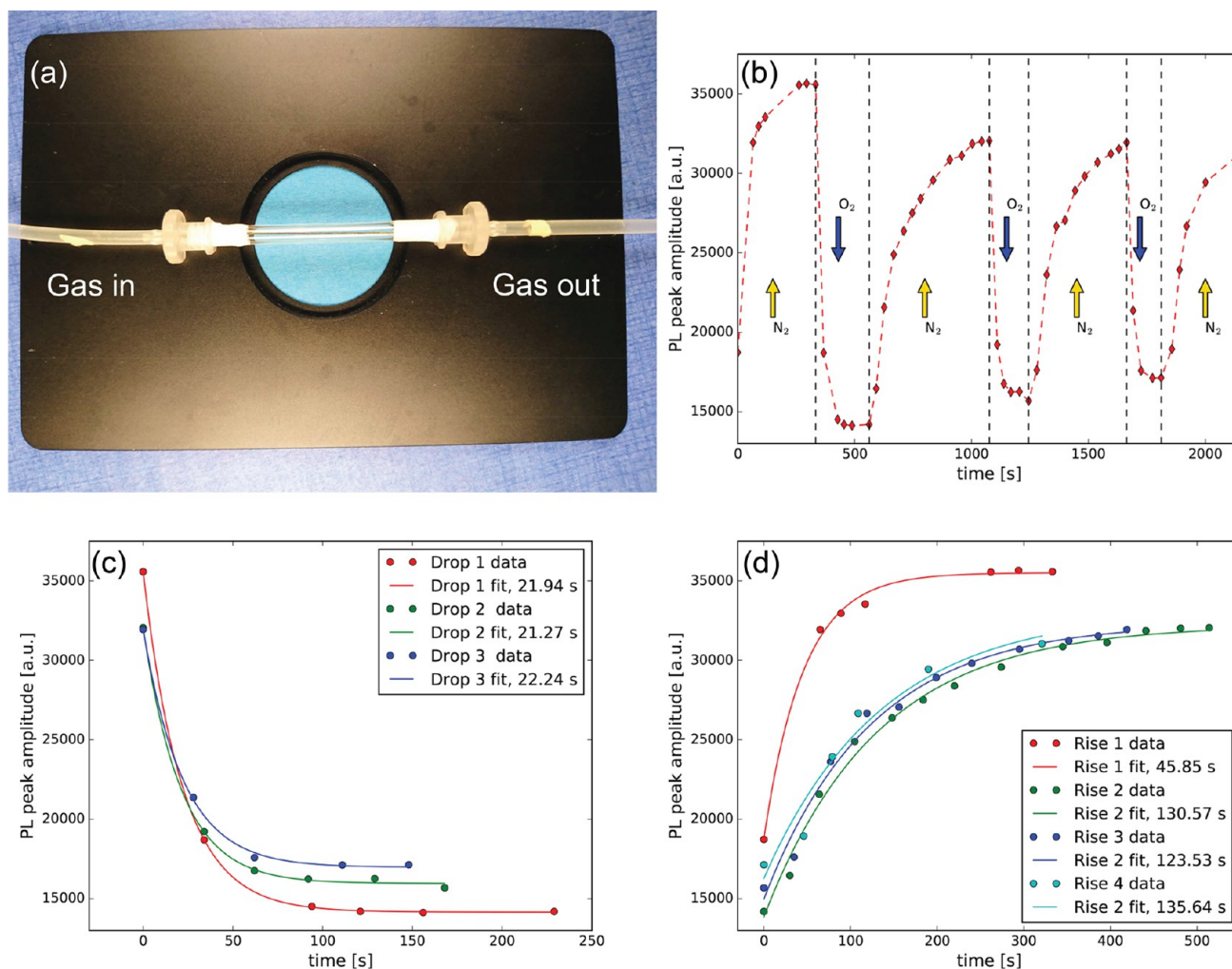


Figure 4. Experimental setup for acquiring PL spectra of MAPbI₃ deposited onto cylinder-shaped substrates under exposure to the flow of various gaseous media and the example time-dependent evolution of the photoluminescent response of the light-soaked devices versus intermittent flow of N₂ and O₂. (a) Assembly consisting of a 330 μm quartz rod coated with MAPbI₃, centrally positioned in a quartz tube (3.0 mm i.d./4.0 mm o.d.) and attached to a microscope sample holder plate. (b) Typical time evolution of the PL signal acquired for MAPbI₃ deposited onto a cylinder-shaped substrate (quartz rod, 330 μm in diameter) under continuous excitation at $\lambda_{\text{exc}} = 546$ nm and intermittent exposure to N₂ and O₂ in the steady-state regime. (c) Overlapped plots of the decreasing portions of the photoluminescent response under exposure to O₂. (d) Overlapped plots of the increasing portions of the photoluminescent response under exposure to N₂. The solid lines correspond to the exponential fits. The steepest plot in (d) corresponds to the initial light-soaking treatment under exposure to the flow of N₂ (red trace).

(80 and 330 μm), encouraged us to check the utility of the cylinder-shaped geometry of MAPbI₃ deposits for prospective detection of gaseous media. Specifically, for designing a model photoluminescent gas-sensing device, a MAPbI₃-covered quartz rod with a 330 μm diameter was chosen and centrally positioned in a short section of a larger quartz capillary (3.0 mm i.d./4 mm o.d.), which served as an external, light-transparent sample holder (Figure 4(a)). For further technical details see Figure S2.

This arrangement enabled us to expose the deposits of micrometer-sized MAPbI₃ wires to various gaseous media and simultaneously collect their PL spectra. The example time-evolution of the photoluminescent response of the freshly prepared MAPbI₃ deposit on a 330 μm diameter quartz rod under continuous illumination with green light ($\lambda_{\text{exc}} = 546$ nm) and intermittent exposure to O₂ and N₂ is shown in Figure 4(b).

As can be seen in Figure 4(b), while interchanging successively the gas flow from N₂ to O₂, the photoluminescent

response of the MAPbI₃ deposit markedly changes. Specifically, under intermittent exposures to N₂ and O₂, the corresponding PL signals undergo a pronounced intensity increase or decrease, respectively. For easier comparison, the overlapped plots of the decreasing and increasing portions of the photoluminescent responses under the intermittent flows of O₂ and N₂ are shown in Figure 4(c and d), respectively. The partial decay and the subsequent partial recovery of the PL signal under exposure to the flow of O₂ and N₂, respectively, was reproducible and could be observed several times during the experiment.

Even though the times of exposure to the two above-mentioned gaseous media were not the same, fitting the exponential decaying (rising) function allowed us to extract the characteristic times corresponding to a decrease (increase) of the PL signal amplitude by ca. 2.7 times. It is then evident that the subsequent exposures to O₂ result in rapid decays of the PL signals, which occur on a time scale of ~ 20 s (Figure 4(c)). In contrast, after switching back to N₂, the photoluminescent response undergoes a phase of recovery, i.e., restores the initial

PL amplitude as in the previous cycle. This process is definitely slower and occurs on a time scale of ~ 130 s (Figure 4(d)). It is worth pointing out that the plot with the steepest slope (red trace in Figure 4(d)) and the corresponding rise time of ~ 45 s was recorded during the initial light-soaking treatment under exposure to the flow of N_2 . The relative changes in the PL signal intensity shown in Figure 4(b) were found to be 50–60%.

Some of the previously reported gas sensors have shown weaker performance in terms of response times as well as usually required a more sophisticated engineering. For example Addabbo et al.³⁴ reported on a $YCoO_3$ -based sensor of CO, NO, and NO_2 via measurements of resistance. In their device they used a heated sensing material: the corresponding working temperatures were 180 °C for sensing NO_x and more than 200 °C for CO. These devices at their best have response times of 0.5–1.5 min and recovery times of 0.6–4.7 min. Another study on gas sensing, this time using the perovskite material $MAPbBr_3$, has been reported by Fang et al.³⁵ Their device was based on the intensity of the PL signal and was sensitive to air, dry O_2 , and moist N_2 . The response times reported for this device were on the order of 1000 s or longer. Compared to the above-mentioned reports, the response times reported herein are definitely shorter, being in the same range as those reported for more sophisticated devices having, for example, a heated substrate.³⁶

The phenomenon of the partial decay of the PL signal under exposure to O_2 has been often reported in the context of the studies of the influence of light and oxygen on the stability of $MAPbI_3$ -based photoactive layers. Although there is a consensus that, in combination with light, oxygen molecules mainly contribute to quenching of the PL emission in microcrystalline deposits of $MAPbI_3$,³⁷ the proposed plausible mechanisms explain only partially the corresponding phenomena.^{38,39} Moreover, there is also growing experimental evidence that in the context of the monocrystalline $MAPbI_3$ an opposite effect, i.e., the PL enhancement, upon exposure to O_2 can also be observed.^{40,41}

The rapid diffusion of oxygen into the microcrystalline deposits of $MAPbI_3$ in combination with photoexcited carriers is considered to be the dominant factors resulting in an enhancement of trapping sites responsible for nonradiative charge recombination.^{42,43} In particular, the total diffusion times into thin layers (typically 500 nm thick) of $MAPbI_3$ have been found to occur on a time scale of 5–10 min.⁴³

Moreover, as can also be seen in Figure 4(b), the subsequent cycles of gas switching from N_2 to O_2 result in an overall decrease of the photoluminescent response observed during the recovery phase (exposure to N_2), as well as in an overall increase of the PL signals acquired at the end of the rapid decay phase (exposure to O_2). This might suggest that although the observed changes in the photoluminescent responses upon successive exposures to O_2 are largely reversible, there is a long-term oxygen-induced photodegradation of $MAPbI_3$.

Thus, at least two different scenarios of oxygen interactions with microcrystalline deposits of $MAPbI_3$ can be invoked. First, a rapid penetration and diffusion of O_2 in parallel with continuous illumination with above-band-gap photons ($h\nu > 1.6$ eV) can activate deep trap centers of the photoexcited carriers, thus leading to an efficient and reversible PL quenching. Second, the diffusion of oxygen molecules into polycrystals of $MAPbI_3$ and their interaction with the photoexcited carriers (electrons) may result in formation of

superoxide radical species ($O_2^{\bullet-}$), which are critical to both the oxygen-induced degradation of the host lattice and concomitant irreversible decrease of the PL emission of $MAPbI_3$.⁴³

CONCLUSIONS

In brief, this work demonstrates for the first time the marked influence of the substrate curvature on the crystallinity and morphology of microcrystalline deposits of $MAPbI_3$ prepared via one-step solution casting.

In particular, $MAPbI_3$ layers deposited on cylinder-shaped quartz substrates with small diameters (80 and 330 μm) proved to be densely packed and consisted of micrometer-sized, needle-shaped wires (1 μm thick and 20 μm long). In contrast, for cylinder-shaped quartz substrates with larger diameters (from 400 to 1800 μm), the variability of the crystalline layers of $MAPbI_3$ with respect to the substrate curvature was substantially less pronounced.

The herein observed size reduction of microcrystallites concomitant with denser coverage of $MAPbI_3$ deposits coated onto quartz cylindrical substrates with diminishing diameters was attributed to both the diminishing substrate heat capacities and, albeit to a lesser extent, the enhanced evaporation rates of the solvent for the substrates with increasing curvatures.

Finally, we also demonstrated that the cylinder-shaped geometry of the densely packed microcrystalline $MAPbI_3$ deposit may serve as a model for simple, low-cost photo-optical devices, including gas sensors.

METHODS

Single-Step Solution Casting of $MAPbI_3$ on Cylinder-Shaped Substrates: Preparation of $MAPbI_3$ Precursor in DMF Solution. Prior to preparing the saturated DMF solutions of $MAPbI_3$ it was important to prepare stoichiometric and pure single crystals. $MAPbI_3$ single crystals were made by precipitation from an aqueous solution of concentrated hydroiodic acid (57 wt % in H_2O) containing stoichiometric amounts of lead(II) acetate trihydrate ($Pb(ac)_2 \cdot 3H_2O$) and methylamine (CH_3NH_2 , 40 wt % in H_2O). $MAPbI_3$ crystals were grown and recrystallized in the saturated hydroiodic acid solution applying a temperature gradient in the vessel. The crystals were dissolved at the higher temperature side of the vessel and recrystallized at the lower temperature side of the vessel.⁴⁴ Subsequently, the thus obtained $MAPbI_3$ single crystals were harvested, dried at 120 °C, and dissolved in DMF, thus leading to a 50 wt % DMF stock solution.

Single-Step Solution-Casting of $MAPbI_3$ on Cylinder-Shaped Substrates: Thin-Film Deposition. All materials for fabrication of $MAPbI_3$ deposits were purchased from Sigma-Aldrich and used as received. The thin polycrystalline layers of $MAPbI_3$ were deposited via one-step solution casting on cylinder-shaped quartz substrates having the following diameters: 80, 330, 400, 700, 1100, and 1800 μm . Prior to the film deposition process, the quartz rods were carefully washed in acetone and ethanol, rinsed with the deionized water, and dried in air. Subsequently, the cylinder-shaped quartz substrates were covered with the stock solution of stoichiometrically mixed $MAPbI_3$ precursors using dipping and doctor-blade techniques.

Finally, the substrates were cured on a hot plate at 110 °C for 10 min. While curing, the rods were positioned at a small distance (3.0 mm) from the hot plate, thus allowing hot air to circulate all over the annealed substrate. The corresponding scheme of the experimental setup is shown in Figure S1. To

avoid interaction with air and moisture, the prepared samples were stored under an inert atmosphere (nitrogen) in sealed glass containers.

Scanning Electron Microscopy Imaging. The morphology of the polycrystalline MAPbI₃ layers deposited on cylinder-shaped quartz rods was investigated by SEM with the help of both secondary electrons and in-lens detectors. All SEM images were collected with a high-performance Schottky field-emission electron microscope capable of resolution in the 2–5 nm size range, model LEO 1550 (Carl Zeiss AG, Jena, Germany), in the Center of MicroNanoTechnology (CMi) at the EPFL. The analysis of the SEM images made it also possible to estimate the thickness of MAPbI₃ films deposited on individual cylinder-shaped quartz substrates.

Evaluation of the Surface Roughness of Quartz Substrates by Atomic Force Microscopy. The surface roughness of uncoated quartz rod substrates was investigated by AFM. The visualization of the surface topography and the 2D roughness profiles were done with an AFM XE-100 from Park Systems Inc. (Santa Clara, CA, USA). The measurements were performed under contact mode using silicon cantilevers, model NSC36-10 M (spring constant of 5.0 N/m), from Park Systems. The analysis of variation of the substrate roughness was conducted with a standard Park Systems software package, XEI.

Optical Microscopy Imaging and Steady-State Photoluminescence Measurements. The optical microscopy imaging under visible light illumination, as well as the luminescence microscopy imaging and collection of the steady-state PL spectra, was performed using a custom-designed setup, which combined an inverted biological epifluorescence microscope (TC5500, Meiji Techno, Japan) with a compact spectrofluorometer (USB 2000+XR, Ocean Optics Inc., USA). A digital noncooled CCD camera (Infinity 2, Lumenera Co., Ottawa, Canada) was used to capture the luminescence images of the studied MAPbI₃ deposits. The PL spectra and luminescence images were collected under illumination with an excitation wavelength $\lambda_{\text{exc}} = 546$ nm. The excitation wavelength was filtered out from the emission spectrum of the microscope's Mercury vapor 100 W lamp by implementing the dedicated set of Meiji Techno filters, model 11002v2 green.⁴⁵

Prior to performing luminescence microscopy imaging and collecting the PL spectra, the cylinder-shaped quartz substrates covered with MAPbI₃ were centrally positioned in short sections of larger quartz capillaries (3.0 mm i.d./4 mm o.d.), which served as external, light-transparent sample holders. Centering the quartz rods inside the quartz tube was achieved by implementing two short sections of coiled copper wires (0.6 mm DIA), to which the terminations of the rods were glued. Afterward, both ends of the quartz tube (sample holder) were connected to the corresponding outlets of gaseous media, i.e., oxygen (O₂), nitrogen (N₂), and argon (Ar), using Luer-type plastic connectors and thin polypropylene flexible tubes. The whole setup was then attached to a microscope sample holder plate, as shown in Figure 4(a).

This approach made it possible to position the sample holder on the microscope XY stage and provided an easy way for the direct delivery of various gaseous media to the MAPbI₃-covered substrate as well as enabled us to detect gas-dependent changes in the characteristic PL spectra of MAPbI₃.

Gas Flow. For our experiments we have used dry oxygen, nitrogen, and argon with a flow rate of ~68 L/h. The flow rate

was regulated and measured by a Swagelock variable area flowmeter (VAF-G2-06M-1-0).

■ ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acsp Photonics.7b01496.

Technical details of the preparation of the samples; details of the setup used for the PL measurements; typical PL spectrum of the samples; additional discussion of differences in morphology; distributions of dimensions of MAPbI₃ microwires for rods of different diameters; discussion of the effects of heat capacity and air-flow; evaluation of surface roughness of quartz substrates; discussion of the solvent evaporation rate from strongly curved surfaces; influence of gas flow on MAPbI₃ PL in the light-soaking regime (PDF)

Video_clip_1.mp4: Comparison of the crystallization kinetics of the 80 and 400 μm deposited solution when the quartz rod is placed on a hot plate after MAPbI₃ solution is applied (ZIP)

Video_clip_2.mp4: Comparison of the crystallization kinetics of the 80 and 400 μm deposited solution when the quartz rod is preheated on a hot plate before MAPbI₃ solution is applied (ZIP)

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Notes

The authors declare no competing financial interest.

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